# NSN 5962-01-132-7848

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# **Overall Height:** 0.400 inches

0.400 menes

Overall Width:

Between 0.590 inches and 0.620 inches

# Body Length:

1.290 inches

#### **Body Width:**

Between 0.500 inches and 0.610 inches

#### **Body Height:**

0.185 inches

#### **Maximum Power Dissipation Rating:**

1.02 watts

**Operating Tempurature Range:** 

#### -55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Burn in and bipolar and monolithic and programmed and schottky

#### **Inclosure Material:**

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

#### Case Outline Source And Designator:

D-3 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# Memory Device Type:

Rom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

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